

International
IR Rectifier

100BGQ100
 100BGQ100J

SCHOTTKY RECTIFIER

100 Amp

Major Ratings and Characteristics

| Characteristics | Values | Units |
|---|-------------|---------|
| $I_{F(AV)}$ Rectangular waveform @ T_C | 100 129 | A °C |
| I_{DC} Maximum | 141 | A |
| V_{RRM} | 100 | V |
| I_{FSM} @ $t_p = 5 \mu s$ sine | 6300 | A |
| V_F @ 100Apk typical @ T_J | 0.74 125 | V °C |
| T_J range | -55 to 175 | °C |



Description/ Features

This Schottky rectifier has been optimized for low reverse leakage at high temperature

The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

- 175°C T_J operation
- High Frequency Operation
- Low forward voltage drop
- Continuous High Current operation
- Guard ring for enhanced ruggedness and long term reliability
- **PowIRtab™ package**

Case Styles

| 100BGQ100 | 100BGQ100J |
|---|--|
|  |  |

Voltage Ratings

| | |
|---|-----------------------|
| Part number | 100BGQ100, 100BGQ100J |
| V_R Max. DC Reverse Voltage (V) | 100 |
| V_{RWM} Max. Working Peak Reverse Voltage (V) | |

Absolute Maximum Ratings

| Parameters | Values | Units | Conditions |
|--|--------|-------|--|
| $I_{F(AV)}$ Max. Average Forward Current | 100 | A | 50% duty cycle @ $T_C = 129^\circ\text{C}$, rectangular waveform |
| $I_{F(RMS)}$ RMS Forward Current | 141 | A | $T_C = 120^\circ\text{C}$ |
| I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current | 6300 | A | 5 μs Sine or 3 μs Rect. pulse |
| | 800 | | 10ms Sine or 6ms Rect. pulse |
| E_{AS} Non-Repetitive Avalanche Energy | 9 | mJ | $T_J = 25^\circ\text{C}$, $I_{AS} = 2$ Amps, $L = 4.5$ mH |
| I_{AR} Repetitive Avalanche Current | 2 | A | Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical |

Electrical Specifications

| Parameters | Values | | Units | Conditions | |
|--|--------|------|------------------|---|---------------------------|
| | Typ. | Max. | | | |
| V_{FM} Forward Voltage Drop (1) (2) | 0.80 | 0.84 | V | @ 50A | $T_J = 25^\circ\text{C}$ |
| | 0.96 | 1.04 | V | @ 100A | |
| | 0.64 | 0.66 | V | @ 50A | $T_J = 125^\circ\text{C}$ |
| | 0.74 | 0.77 | V | @ 100A | |
| I_{RM} Reverse Leakage Current (1) | 22 | 300 | μA | $T_J = 25^\circ\text{C}$ | $V_R = \text{rated } V_R$ |
| | 14 | 18 | mA | $T_J = 125^\circ\text{C}$ | |
| $V_{F(TO)}$ Threshold Voltage | 0.484 | | V | $T_J = T_J \text{ max.}$ | |
| r_t Forward Slope Resistance | 2.0 | | m Ω | | |
| C_T Max. Junction Capacitance | 1320 | | pF | $V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C | |
| L_S Typical Series Inductance | 3.5 | | nH | Measured from tab to mounting plane | |
| dv/dt Max. Voltage Rate of Change (Rated V_R) | 10000 | | V/ μs | | |

(1) Pulse Width < 300 μs , Duty Cycle < 2%(2) $V_{FM} = V_{F(TO)} + r_t \times I_F$

Thermal-Mechanical Specifications

| Parameters | Values | Units | Conditions |
|---|------------|--------------------|--------------------------------------|
| T_J Max. Junction Temperature Range | -55 to 175 | $^\circ\text{C}$ | |
| T_{stg} Max. Storage Temperature Range | -55 to 175 | $^\circ\text{C}$ | |
| R_{thJC} Max. Thermal Resistance Junction to Case | 0.50 | $^\circ\text{C/W}$ | DC operation |
| R_{thCS} Typical Thermal Resistance, Case to Heatsink | 0.20 | $^\circ\text{C/W}$ | Mounting surface, smooth and greased |
| wt Approximate Weight | 5(0.18) | g(oz.) | |
| T Mounting Torque | Min. | 1.2(10) | N*m (lbf-in) |
| | Max. | 2.4(20) | |
| Case Style | PowIRtab™ | | |

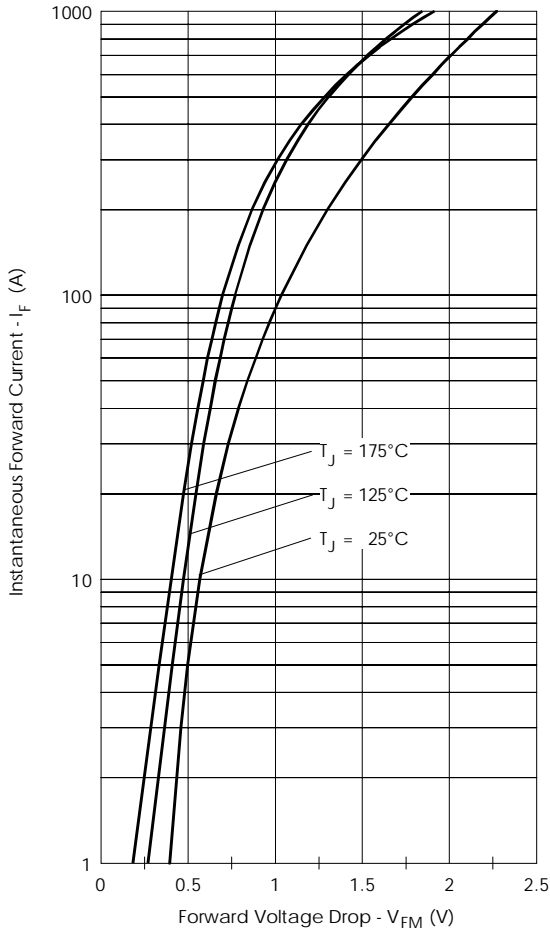


Fig. 1 - Maximum Forward Voltage Drop Characteristics

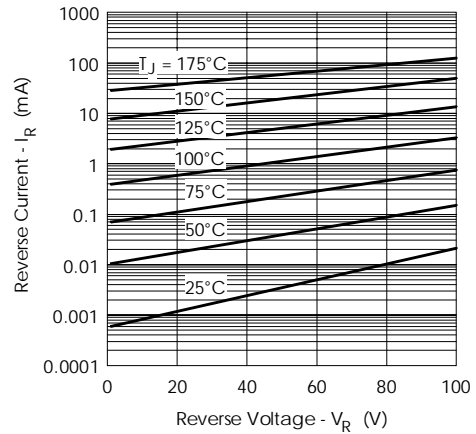


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

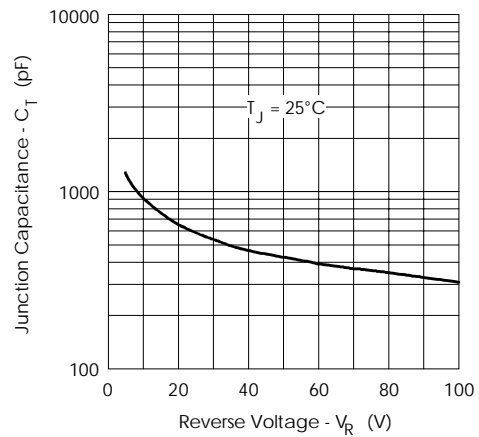


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

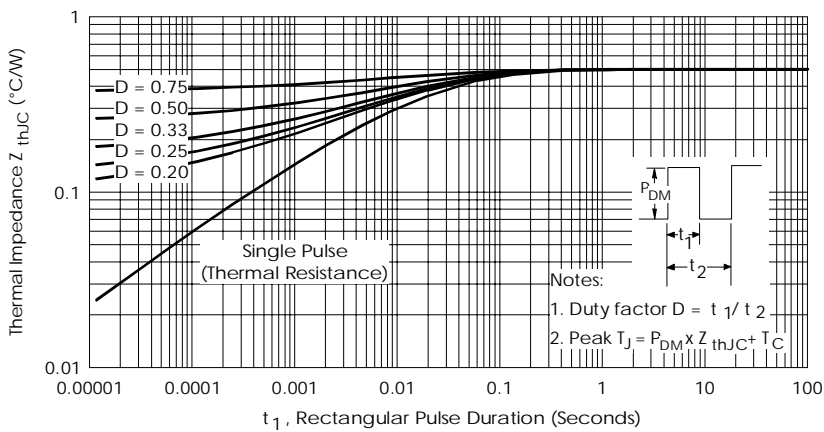


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

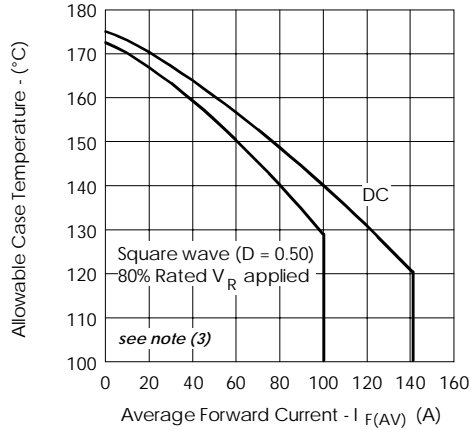


Fig.5- Maximum Allowable Case Temperature Vs. Average Forward Current

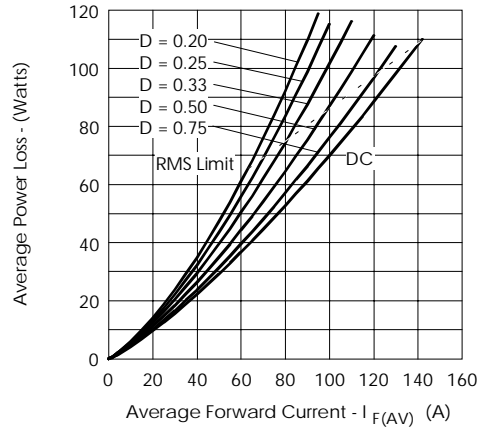


Fig.6- Forward Power Loss Characteristics

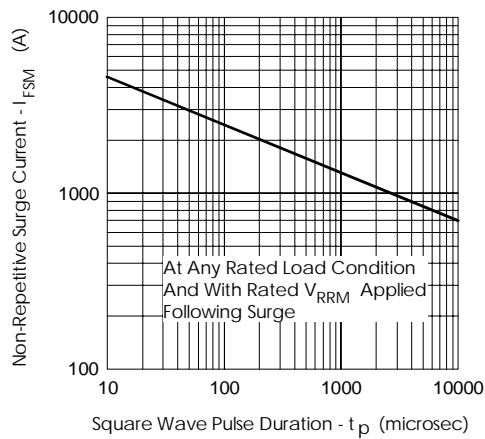


Fig.7- Maximum Non-Repetitive Surge Current

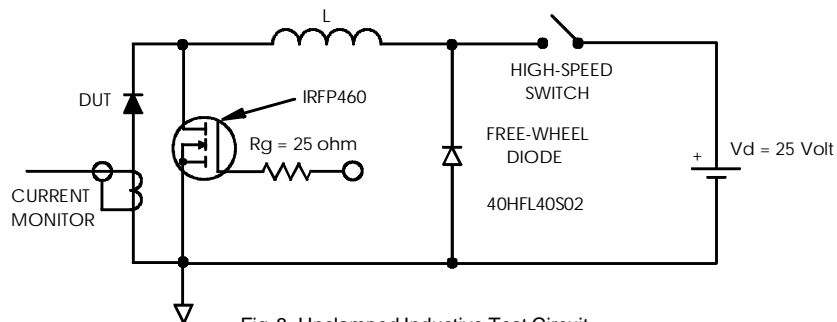


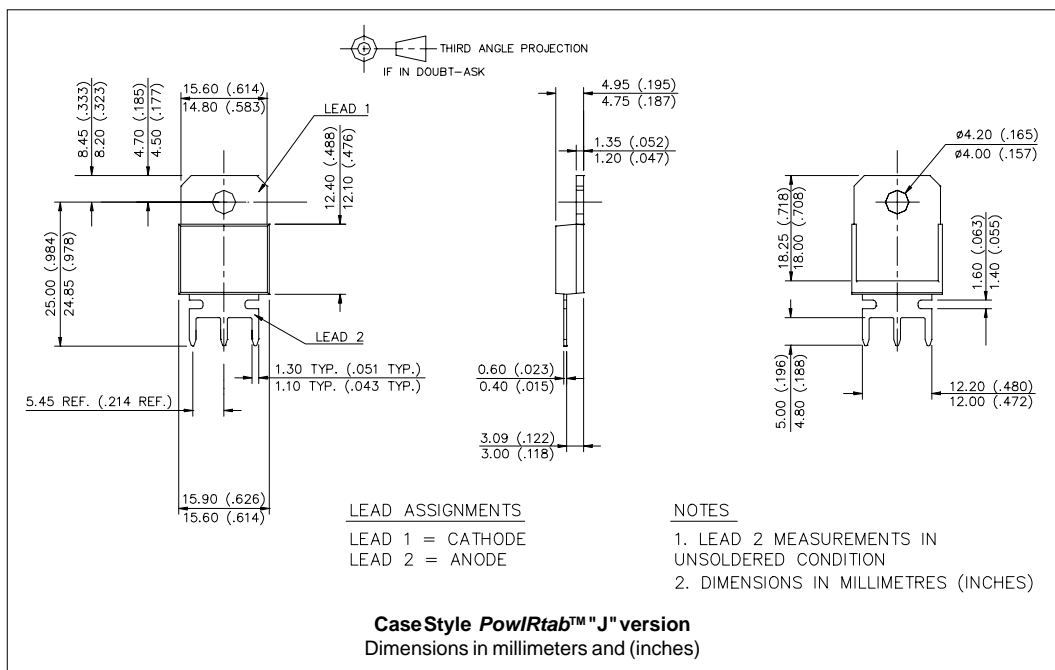
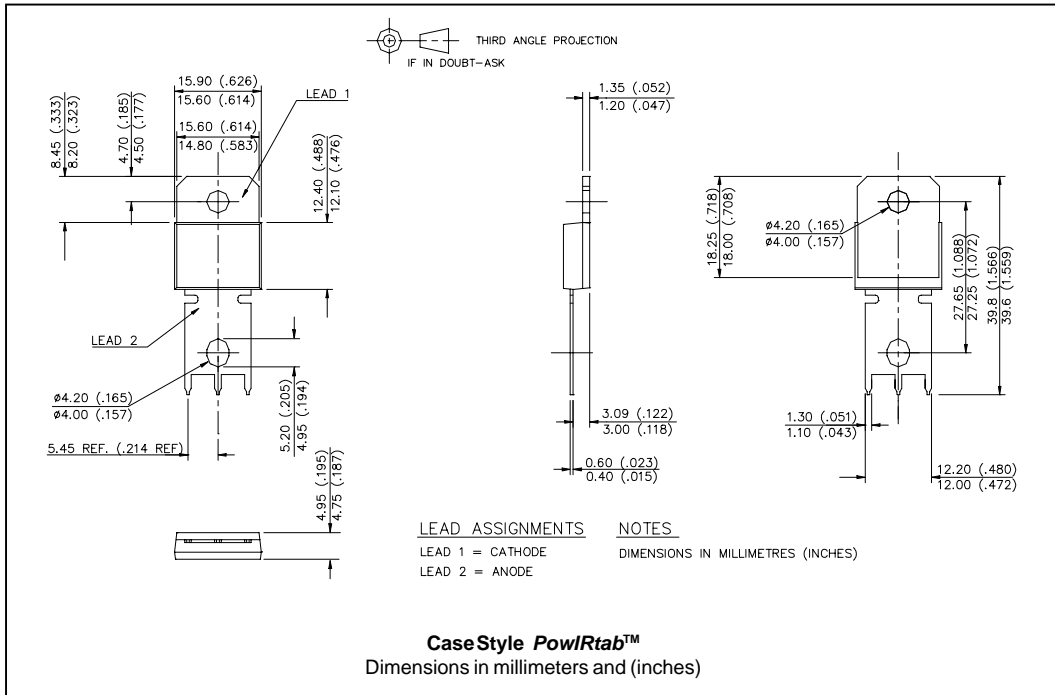
Fig.8- Unclamped Inductive Test Circuit

(3) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

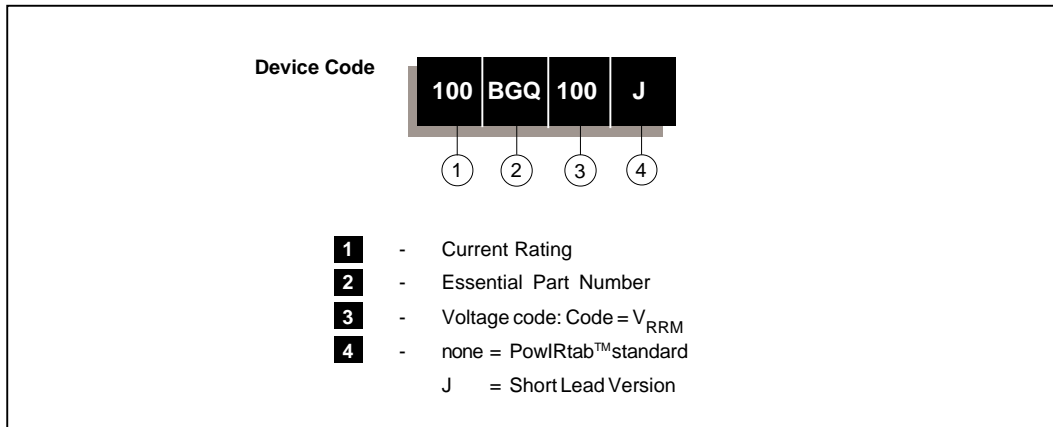
P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

Outline Table



Ordering Information Table



Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.